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Organic laser molecule with high-mobility, high photoluminescence quantum yield and deep-blue lasing characteristics

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ABSTRACT: Here, we design and synthesize an organic laser molecule, 2,7-diphenyl-9H-fluorene (LD-1), which has the state-ofthe-art integrated optoelectronic properties with high mobility of 0.25 cm² V⁻¹ s⁻¹, high photoluminescence quantum yield of 60.3 % and superior deep-blue laser characteristics (low threshold of $P_{th} = 71$ uJ cm⁻² and $P_{th} = 53$ uJ cm⁻² and high quality factor (Q) of ~3100 and ~2700 at emission peaks of 390 nm and 410 nm, respectively). Organic light-emitting transistors based on LD-1 are for the first time demonstrated with obvious electroluminescent emission and gate tunable features. This work opens the door for a new class of organic semiconductor laser molecules, and is critical for deep-blue optical and laser applications.

■ INTRODUCTION

Organic laser semiconducting molecules are the basis of organic light emitting transistors (OLETs) and electrically pumped organic laser (EPOLs), which demonstrate great promise for smart display technology, organic lasers, biosensing and other related optoelectronic circuits.¹⁻⁵ However, it remains a big challenge for the development of molecules for OLETs and EPOLs over the past decades.⁶⁻¹¹ One of the key restrictive factors is the design motif integrating high mobility, strong emission for efficient electrooptic conversion, and ideal laser characteristics to achieve sufficiently high number of excited states under high current density to initiate lasing.^{8,9,12,13} Designing highly π -extended fused conjugated systems is one effective approach to increasing charge transport for high mobility,¹⁴⁻¹⁶ however, such kind of molecules always show very weak fluorescence in solid state due to the significant quenching of excited states induced by condensed molecular packing and remarkable singlet fissions.^{17,18} Reducing the π -conjugation and intermolecular interactions enough may enhance the fluorescence efficiency of organic materials, but generally at the cost of efficient charge transport property.¹⁹⁻²¹ More recently, achievement of high mobility emissive organic semiconductor,²²⁻²⁶ high-efficiency OLETs^{6,7,27,28} and the exciting indication of current-injection lasing from an organic semiconductor²⁹ have been demonstrated, which brings the hope and passion of scientists from different fields to this field research. Generally speaking, to date such materials are still very limited, and only very few of them could meanwhile possess the characteristic of amplified spontaneous emission (ASE) phenomenon at reasonably low pump intensities, not to mention simultaneously possessing good optical gain for lasing character.^{8,9,30-32}

Here, we design and synthesize a fluorene-based organic semiconductor, 2,7-diphenyl-9H-fluorene (LD-1) (Figure 1a), with efficient charge transport, strong emission as well as superior lasing character. The molecule design concept of LD-1 compound is as following: i) fluorene as the unit core is intrinsically a superior building blocks for organic lasers;^{8,31} ii) it is easily to get derivatives at 2,7 positions for extending π conjugation and modulating molecular arrangement to enhance the charge transport; iii) it is also a promising building block for designing blue emitting materials,³³⁻³⁵ which is particularly important in displays and lasing but difficult to be achieved, and finally iv) the introduction of rotational carbon-carbon bond for extending π -conjugation could modulate both optical and electrical properties for their good integration.^{12,22-24,36} Indeed, experimental results demonstrate that LD-1 compound well integrates the properties of highmobility charge transport and strong luminescence with carrier mobility of 0.25 cm² V⁻¹ s⁻¹ and photoluminescence quantum vield (PLOY) of 60.3 % for its single crystals. Moreover, deep-blue-emissive whispering-gallery-mode (WGM) laser is demonstrated with a low threshold of 71 µJ cm⁻² and 53 µJ cm⁻ ² and high cavity quality factor (Q) of 3100 and 2700 at emission peaks of 390 nm and 410 nm, respectively. To our knowledge, LD-1 is amongst the best performance of deepblue organic semiconductor laser integrating efficient charge transport property reported in the literatures (Table S1, S2). These attractive features of LD-1 make it be a good candidate for the research of integrated optoelectronic devices.

RESULTS AND DISCUSSION

LD-1 was synthesized from 2,7-dibromofluorene and phenylboronic acid using palladium-catalyzed Suzuki coupling reaction with a high yield of 63 % (Scheme S1). After vacuum-sublimation purification process, milky white powder was obtained. Strong blue emission is easily observed under UV light illumination in both cases of solution and powder, giving a high PLQY of 65 % and 50 %, respectively (Figure S1). The highest occupied molecular orbital (HOMO) of -5.76 eV was calculated based on cyclic voltammetry (CV) measurement curve (Figure S2), and the lowest unoccupied molecular orbital (LUMO) of -2.72 eV was further calculated based on the HOMO level and an energy band of 3.04 eV is obtained from its UV-vis curves which will be shown in following section. Good thermal stability of LD-1 with sublimation temperature of 337 °C was characterized from thermal gravimetric analysis (TGA) (Figure S3). Large-sized single crystals of LD-1 were obtained *via* a slow evaporation process from the saturated mixture solution of CH₂Cl₂:ethanol = 1:2 at room temperature. X-ray crystallographic data

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demonstrates that the LD-1 crystal belongs to orthorhombic system with cell parameters of a = 5.8687 (2) Å, b = 33.6814(8) Å, c = 8.4453 (3) Å (CCDC: 1942276 Table S3). As indicated by single crystal data, a slight rotation angle of 26.01° and 14.00° is determined for the two π -extended benzene rings (left and right) relative to the fluorene core due to the rotation effect of C-C bond (Figure 1b), which is beneficial for the reduce of fluorescence quenching effect.²²⁻ ^{24,36} Under the balance of C-C bond, good electron distributions on the whole molecule at both HOMO and LUMO levels are also demonstrated, which is favorable for forming strong intermolecular interactions to achieve efficient charge transport. A typical herringbone molecular packing mode with a herringbone angle of 64.08° is adopted by LD-1 in single crystals where multi strong C–H– π interactions (2.730-2.891 Å) between neighboring molecules are formed (Figure S4). All the results suggest the capacity of LD-1 to integrate strong fluorescence and efficient charge transport properties together.



Figure 1. (a) Chemical structure of LD-1 molecule and (b) the views of LD-1 molecule seeing perpendicular (top) to and along (side) the conjugated plane of fluorene core. (c) Fluorescent image of LD-1 single crystals obtained through PVT technique. (d) XRD patterns of LD-1 single crystals (inset is a schematic of the elongated hexagon LD-1 crystals with the indexed diffraction planes according to structure analysis). (e) TEM image of an individual crystal and its corresponding SAED pattern. Scale bar: 2 μ m. (f) Two-dimensional charge transport routes in LD-1 crystals with herringbone molecular packing.

To further investigate the charge transport and optical property of LD-1, high-quality micro/nano-single crystals of LD-1 were prepared by physical vapor transport (PVT). Slightlyelongated hexagon LD-1 crystals with a side-length (W_1 (long edges)/ W_2 (short edges)) ratio centered at around 1.8 based on 100 crystals were usually obtained (**Figure S5**), which have

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smooth surface (root mean square (RMS): 0.789 nm) and thickness of around 100 nm characterized by atomic force microscopy (AFM) (Figure S6). A high PLQY of 60.3% was determined for single crystals of LD-1 (Figure 1c), which is slightly lower than that of LD-1 in solution due to the aggregation effect but still maintain the strong emission characteristic, even in single crystal state. Under 330-380 nm light illumination, typical optical waveguide feature was observed for LD-1 crystals with a manifestation of very bright emission from their crystal edges suggesting the high quality of the obtained LD-1 crystals, which is a crucial parameter for high optical gain to initiate lasing. Figure 1d shows the X-ray diffraction (XRD) patterns of LD-1 micro/nano-crystals grown on Si/SiO₂ substrate where a series of very sharp and strong diffraction peaks were observed. These diffraction peaks could be well indexed by (0k0) reflections based on single crystal data of LD-1, giving a layer-by-layer growth mode along baxis with a interlayer *d*-spacing of 33.94 Å, indicating that the long axis of LD-1 molecule is nearly standing on the substrate (Figure S7a). Figure 1e shows the transmission electron microscopy (TEM) image of an individual LD-1 single crystal and its corresponding selected area electron diffraction

(SAED) pattern, which was taken by directing the electron beam perpendicular to the flat surface of individual LD-1 single crystal. The bright and strong multi-order diffraction peaks further confirm the high crystallinity of LD-1 micro/nano-crystals. Based on the LD-1 crystal cell parameters, the spots in the white square and green circle can be ascribed to the Bragg reflections of (001) and (100) planes with $d_{(001)} = 8.46$ Å and $d_{(100)} = 5.93$ Å, respectively. Combining XRD and SAED results together, a schematic of LD-1 crystal planes in hexagon morphology is shown in inset of Figure 1d, where the crystals (010) and ($\overline{010}$) crystal planes are on the top and bottom bound by (002), $(\overline{002})$, $(\overline{101})$, $(10\overline{1})$, (101) and $(\overline{101})$ crystal planes on the six side-faces, $\angle (00\overline{2})/$ $\angle (10\overline{1}) = 125^{\circ}, \angle (10\overline{1})/$ $\angle(101) = 110^{\circ}$ (Figure S7b). As shown in Figure 1f, an efficient two-dimensional charge transport network is formed in direction of ac planes, which is parallel to the substrate. In this case, if one molecule gains a charge, it can quickly transfer to the two neighbors, and then onto the surrounding molecules, forming a two-dimensional network, which would ensure high mobility in planar organic field-effect transistors (OFETs).14,37



Figure 2. (a) UV-*vis* absorption, PL and ASE (filled area) spectra for the LD-1 in CH_2Cl_2 solution and crystals. (b) CIE 1931 coordinates of the LD-1 crystals. (c) Time-resolved peak fluorescence of LD-1 in CH_2Cl_2 solution and crystals. (d) Schematic graph of the 4-energy level of LD-1 molecule and the HOMO and LUMO in crystals.

The photophysical properties of LD-1 in solution and single crystal state were systematically investigated. **Figure 2a** shows the UV-*vis* absorption and photoluminescence (PL) spectra of LD-1 in dichloromethane (CH₂Cl₂) solution (dashed lines) and crystals (solid lines) as well as the amplified spontaneous emission (ASE) spectra of LD-1 crystals. Key photophysical parameters measured for LD-1 are summarized

in **Table 1**. A high molar absorption coefficient of 4.4×10^4 M⁻¹ cm⁻¹ at 323 nm was determined for LD-1 in dilute CH₂Cl₂ solution, a primary parameter ensuring for its strong emission. In comparison with that of solution absorption, an obvious bathochromic-shift with the main peaks located at 353 nm is demonstrated for LD-1 crystals, which is one indication of J-aggregation in crystals. PL spectra demonstrate that the main

emission peak of LD-1 crystal is red-shifted to 407 nm, suggesting LD-1 is a deep- blue emission semiconductor. As we know that, it still remains an urgent task to develop high performance deep-blue emissive organic semiconductors though it is great crucial in organic optoelectronic devices. According to the National Television Standards Committee (NTSC), the calculated Commission Internationale de l'Éclairage (CIE) coordinates of LD-1 are (0.16, 0.07) (Figure **2b**), which are very close to the standard blue CIE coordinates of (0.14, 0.08), suggesting LD-1 is also one of the very few blue emissive organic semiconductors reported so far.³⁸⁻⁴⁰ The superior deep-blue character of LD-1 with CIE y < 0.10suggests its great potential for blue optical and laser applications. The time-resolved fluorescence spectra shown in **Figure 2c** reveals the reduced fluorescence lifetime (τ) for LD-1 crystals (1.90 ns) compared to that of its CH₂Cl₂ solution (2.83 ns) when fitted by a double-exponential decay model (Table S4). Correspondingly, fast radiative deactivation rates $(k_r = \Phi_F / \tau_{FL})$ of 3.16×10^8 s⁻¹ and 2.30×10^8 s⁻¹ are determined for LD-1 in crystals and solution, respectively, suggesting the efficient emission of LD-1 both in solution and crystals. Typical ASE property was further characterized for LD-1 single crystals when using a 355 nm pulsed laser as the excitation source along with increase of the pulse energy

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(Figure 2a and Figure S8). A narrowed bandwidth of PL spectrum with a half-maximum (FWHM) of 9.66 nm was observed for LD-1 crystals and a sharp ASE peak is located at 407 nm, which is well consistent with that of its PL spectrum. A threshold energy of 168 uJ cm⁻², high gain coefficient (48 cm⁻¹), and low loss coefficient (5.29 cm⁻¹) were further characterized based on the deep investigations at the ASE peak (Figure S9). In addition, according to the theoretical calculation (Figure 2d, Figure S10 and Table S5), a wellseparated four-energy level is formed between the ground state S_0 and the first excited state S_1 . Consisting of 96.6 % local transition from the HOMO to the LUMO, S₁ is a highly luminescent state with a calculated transition dipole moment larger than 12 Debye. After being excited to S_1 state, the molecule will immediately relax to the lowest vibrational level of S_1 (E₃). Spontaneous and stimulated emission will then take place from E₃ to E₂, followed by another immediate vibrational relaxation process to E1. This four-energy level system guarantees that more luminophores populates on the E₃ than E_2 . A large Stokes shift is observed in both the spectra and the four-energy level graph. All the results demonstrate that LD-1 is a superior deep-blue organic semiconductor with very strong emission, good optical waveguide emission and ASE property for organic solid-state laser.

Table 1. A summary of photophysical properties of LD-1 in CH₂Cl₂ solution and crystals.

LD-1	$\lambda_{abs}{}^a [nm]$	$\epsilon_{max}{}^a \left[M^{-1} cm^{-1}\right]$	$\lambda_{em}{}^a [nm]$	$\Phi_{\text{F}}{}^{\text{a,b}}$	$\tau_{FL}{}^{c}$ [ns]	$k_r^d [s^{-1}]$	$k_{nr}^{e} [s^{-1}]$
In solution	307 323	4.4×10 ⁴	356 368	0.65	2.83	2.30×10 ⁸	1.24×10 ⁸
crystals	353		407	0.60	1.90	3.16×10 ⁸	2.11×10 ⁸

^a In CH₂Cl₂ solution (1 × 10⁻⁵ M). ^b Φ_F of the absolute photoluminescence quantum yield (PLQY) *via* using the integrating sphere. ^c Fluorescence lifetime. ^d Radiative deactivation rate calculated according to the $k_r = \Phi_F/\tau_{FL}$ equation. ^e Non-radiative deactivation rate calculated according to the $k_{nr} = 1/\tau_{FL} - k_r$ equation.

Encouraged by the above results, we further investigated the lasing characteristics of LD-1 crystals (Figure 3). Obviously, two main lasing peaks located at 390 nm and 410 nm were evolved in the PL spectra along with increasing the pulse density (Figure S11), demonstrating a multi-mode lasing characteristic as evidenced by the high-resolution PL spectra shown in Figure 3a and Figure 3d. As can be seen that the two PL spectra display a broad spontaneous emission at low pump density excitation when the pump density exceeds the threshold (P_{th}) of 71 uJ cm⁻² at 390 nm and P_{th} = 53 uJ cm⁻² at 410 nm, respectively (Figure 3b and Figure 3e), a set of sharp peaks merging on the top of spontaneous emission spectra. In addition, the intensity dependence is fitted according to the power law x^p equation.⁴¹ The latter p = 2.99 ± 0.15 (390 nm) and $p = 1.85 \pm 0.05$ (410 nm) above the threshold were further calculated, indicating a superlinear regime with typical characteristic of laser emission. As shown in the left inset of Figure 3b, the strong deep-blue laser emission occurs on the top four edges of LD-1 single crystal, indicating that the LD-1 single crystal can act as an efficient 2D micro-resonator of whispering-gallery-mode (WGM). It could be deduced that the light was totally reflected by the four edges and transported along an oblong route in the crystal as shown in inset of Figure 3e. To confirm the WGM micro-resonator, the dependence of the spacing between adjacent modes ($\Delta\lambda$) on optical path length (L) of LD-1 single crystals were further characterized (Figure 3g). Clearly, the mode spacing $\Delta\lambda$ gradually decreases and exhibits more and more modes with the increase of the optical path length L. Specifically, $\Delta\lambda_{390} =$ 0.73, 0.59, and 0.48 nm were observed for length L = 17, 23, and 30 µm at emission peak of 390 nm, and similar phenomenon was also observed for lasing emission peak at 410 nm with $\Delta\lambda_{410} = 1.11$, 0.91, and 0.78 nm for length L = 17, 23, and 30 µm. Such evolution between $\Delta\lambda$ and length L well corresponds to the characteristic of WGM cavity.^{42,43} To further understand the resonant mode and the relationship of WGM cavity and mode spacing, the following the equation is used:

$$\Delta \lambda = \frac{\lambda^2}{L[n - \lambda(dn/d\lambda)]}$$

where $\Delta\lambda$ is the spacing between adjacent modes (Figure S12), $[n - \lambda(dn/d\lambda)]$ is the group refractive index,^{42,43} according to geometric conditions, the optical path length (L) within the resonator could be expressed as

$$L = 2 (W_1 + W_2 \times \text{Sin55}^\circ)$$

where W_1 and W_2 are the edge lengths of the LD-1 single crystal (inset image in **Figure 1d**). The linear increase of $\Delta\lambda$ along with that of increasing 1/L further confirms the formation of WGM-mode cavity for both the two lasing peaks of 390 nm and 410 nm (**Figure 3h**). In addition, the cavity

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quality factor, another important lasing parameter is also investigated with the equation of $Q = \lambda/\Delta\lambda_L$, where λ is the lasing peak wavelength and $\Delta\lambda_L$ is the FWHM of the lasing peak (**Figure S12**), a significant parameter to evaluate a laser micro-cavity.⁴⁴ Very high experimental Q factors of ~3100 at 390 nm and ~2700 at 410 nm were obtained (**Table S6**), which are well consistent with that of simulated Q values of 3088 at 390 nm and 2600 at 410 nm (Figure 3c and Figure 3f). Furthermore, LD-1 single crystals demonstrated good lasing stability during our experimental measurement, which is important for its potential applications.



Figure 3. High-resolution PL spectra of the laser emission around 390 nm (a) and 410 nm (d) under different pump densities. (b) Integrated area of the peak 390 nm as a function of pump density. The lasing threshold is identified as the intersection between the sublinear and superlinear regions. Inset: forth bright PL edges of the LD-1 single crystal under 355 nm fs laser excitation. (e) Integrated area of the peak (410 nm) as a function of pump density. Inset: illustrate a typical optical-ray analysis within WGM- LD-1 microcavity. Optical mode simulation results for a LD-1 single crystal with $W_1 = 18 \mu m$ and $W_2 = 9 \mu m$, Q = 3088 of $\lambda = 390$ nm (c) and Q = 2600 of $\lambda = 410$ nm (f). (g) High resolution PL spectra of laser emission recorded above the threshold for LD-1 with L = 17, 23, and 30 μm . (h) Mode spacing $\Delta\lambda$ at $\lambda = 390$ nm and 410 nm versus 1/L of the LD-1 crystals, showing a clear linear relationship.

Furthermore, the charge transport property of LD-1 was investigated based on organic field-effect transistors (Figure **S13**). Due to the extension of π -conjugation in LD-1 compound ensuring strong intermolecular couplings, efficient electrical transporting property was confirmed for LD-1 with the saturation charge carrier mobility up to 0.25 cm² V⁻¹ s⁻¹ calculated from the typical transfer curves of organic fieldeffect transistors according to the equation of I_{DS} = $(\mu WCi/2L)(V_G - V_T)^2$ (Figure S14) which is more than one order of magnitude higher than that previously reported for fluorene-based organic laser semiconductors (Figure S15 and Table S2). The integration of superior optical and electrical transport properties for LD-1 compound (as summarized in
 Table 2) ensures its application in integrated optoelectronic
device. As an example, OLET, which is possibly the minimized integrated optoelectronic device and also one of the promising device structures for study of EPOLs was further investigated. Figure 4a shows the schematic image of LD-1based OLET where vacuum-deposited LD-1 thin film is used

as the emitting layer and N,N'-Bis (naphthalen-1-yl) -N,N'-bis (phenyl)-benzidine (NPB) is hole injection layer and (3,3'-[5'-[3-(3-Pyridinyl)phenyl][1,1':3',1"-terphenyl]-3,3"-

diyl]bispyridine) (TmPypB) is electron injection layer, respectively. A vertical OLET structure was adopted here with the consideration of its intrinsically short conducting channel for high current density and feasible incorporation of optical configuration and distributed feedback geometry for efficient electroluminescence performance and or initiating lasing.^{3,45} Figure 4b shows the energy alignment of NPB, LD-1, TmPypB and the source electrode of graphene. Due to the tunable Fermi level of graphene and thus the Schottky barrier between bottom graphene and NPB hole injection layer under negative and positive gate voltages, the OLET device can be operated in the on and off states (Figure S16). Furthermore, using other typical electron transporting material, 1,3,5-tris(2-N-phenylbenzimidazolyl)benzene (TPBi) replace of TmPypB, another device structure of Si/ SiO2/ Graphene (Gate)/ NPB/LD-1/TPBi/LiF/Al/Ag was also constructed in the experiment. These two devices demonstrated similar electroluminescence phenomenon with strong emission. Typical electrical and optical output characteristics of LD-1 OLETs (**Figure 4c**) demonstrate a clear and consistent correlation between the current density and emitting light output power, suggesting the good tunability of such device under applied gate voltages. When applied V_{DS} of -20 V and V_{GS} of -60 V, a current density of around 32 mA cm⁻² was obtained and strong blue electroluminescence was observed as shown in **Figure 4d** with uniform emitting character on the overall active region. The intensity of electroluminescence spectra could be obviously increased along with the increase of negative V_G (**Figure S17**), which is consistent with that of PL spectrum of LD-1 thin films (**Figure S18**) with different

relative intensity for emission peaks, probably due to the complex effects induced by different molecular packing structures, optical resonator effect and interface effect in the electrically-driven electroluminescent devices. In addition, compared to molecules in solution,⁴⁶ LD-1 molecules in single crystal state show relatively good stability under both electrical field and 355 nm pulse laser, which is important for potential device applications. More deep research works are still needed in future with the emphasis of constructing appropriate device geometry with optimized molecular packing structure, high quality interface contact, integration of photonic structure and pumping the devices with electrical pulse signal.^{29,47-51}



Figure 4. (a) Schematic of LD-1 based OLET device. (b) Energy level diagram of graphene, NPB, LD-1, TmPypB and the thickness of each layer used in the device. (c) Typical optical and electrical output characteristics of LD-1 OLET. (d) The color-coded images of LD-1-OLET extracted from light emission captured by CCD.

Table 2. Key optoelectronic properties of LD-1 compound in single crystal state.											
Material	λ_{abs} [nm]	λ _{em} [nm]	PLQY	λ _{ASE} [nm]	Gain [cm ⁻¹]	Loss [cm ⁻¹]	P _{th} ^{Laser} [uJcm ⁻²]	Q	Mobility [cm ² V ⁻¹ s ⁻¹]	V _T [V]	I _{on/off}

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LD-1	353	407	60.3 %	407	48	5.29	71 [390 nm] 53 [410 nm]	3100 [390 nm] 2700 [410 nm]	0.25	6	10 ⁶
CONCLUSIONS						organic light	-emitting tran	sistors for a	ctive matrix	Displays.	

CONCLUSIONS

In conclusion, an organic laser molecule, LD-1 was designed and synthesized by introducing phenyl units into the emissive fluorene core via a rotational carbon-carbon bond. Efficient charge transport with carrier mobility of 0.25 cm² V⁻¹ s⁻¹ and strong solid-state emission with PLOY of 60.3 % are demonstrated. Moreover, its single crystals exhibit unique ASE phenomenon with outstanding deep-blue laser character of low thresholds of 71 µJ cm⁻² and 53 µJ cm⁻² and high quality (Q) factor of ~3100 and ~2700 at emission peaks of 390 nm and 410 nm, respectively by WGM resonator. As an example of LD-1 in integrated optoelectronic device application, OLET based on LD-1 was demonstrated. The importance of this work is that i) we present a superior organic optoelectronic compound, LD-1, that well simultaneously integrates high charge carrier mobility, strong photoluminescence, excellent lasing character as well as rare and commendable deep-blue optical property; ii) it opens a door for further developing a series of more efficient organic laser semiconductor towards compact, low-cost display and laser technology. More systematic research works are ongoing and we believe much higher performances would be expected in future by further rational molecular design and device optimization.

ASSOCIATED CONTENT

Supporting Information.

Experimental details, synthesis, characterization, device fabrication, and theoretical studies (PDF). The Supporting Information is available free of charge on the ACS Publications website.

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Notes

The authors declare no competing financial interest.

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